NSN 5961-00-370-1914

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View Online at https://aerobasegroup.com/nsn/5961-00-370-1914 **Inclosure Material:** Metal all transistor **Overall Length:** 0.250 inches all transistor **Terminal Length:** 1.500 inches all transistor **Overall Diameter:** 0.352 inches all transistor **Internal Configuration:** Junction contact all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 all transistor **Electrode Internally-electrically Connected To Case:** Base all transistor **Internal Junction Configuration:** Pnp all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Terminal all transistor **Terminal Circle Diameter:** 0.200 inches all transistor **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium all transistor Voltage Rating In Volts Per Characteristic: -30.0 collector to base voltage, dc all transistor and -25.0 emitter to base voltage, dc all transistor **Current Rating Per Characteristic:** -300.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 150.0 milliwatts small-signal input power, common-collector preset all transistor **Terminal Type And Quantity:** 3 uninsulated wire lead all transistor Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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